

**BT232W-800ET** 

4Q Triac Rev.01 - 09 January 2025

**Product data sheet** 

### **1. General description**

Planar passivated sensitive gate four quadrant triac in a SOT223 surface-mountable plastic package intended for applications requiring direct interfacing to logic level ICs and low power gate drivers.

### 2. Features and benefits

- Direct interfacing to logic level ICs
- · Direct interfacing to low power gate drive circuits
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Sensitive gate in four quadrants
- Surface-mountable package
- Triggering in all four quadrants

## 3. Applications

- General purpose low power motor control
- Home appliances
- Industrial process control
- Low power AC Fan controllers

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit
Absolute	e maximum rating						
$V_{\text{DRM}}$	repetitive peak off-state voltage				800		V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T <sub>sp</sub> ≤ 106 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>			2		A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 20 ms; Fig. 4; Fig. 5		16 18		A	
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms					А
Tj	operating junction temperature			-40 to 150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	-	10	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T <sub>i</sub> = 25 °C; <u>Fig. 9</u>		-	-	10	mA

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Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	Static characteristics						
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>		-	-	10	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 2 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>		-	1.3	1.6	V
Dynamic	Dynamic characteristics						
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 536 \text{ V}; \text{ T}_{\text{j}} = 110 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit; Fig. 14		50	-	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_{D}$ = 400 V; T <sub>j</sub> = 110 °C; dI <sub>com</sub> /dt = 0.44 A/ms; gate open circuit		2	-	-	V/µs

# **5. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		Ν
2	T2	main terminal 2		
3	G	gate		sym051
4	T2	main terminal 2		

# 6. Ordering information

Table 3. Ordering information						
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BT232W-800ET	SOT223	BT232W-800ETF	Reel	4000	SOT223	16-Mar-2006

# 7. Marking

Table 4.	Marking	codes
100010		00400

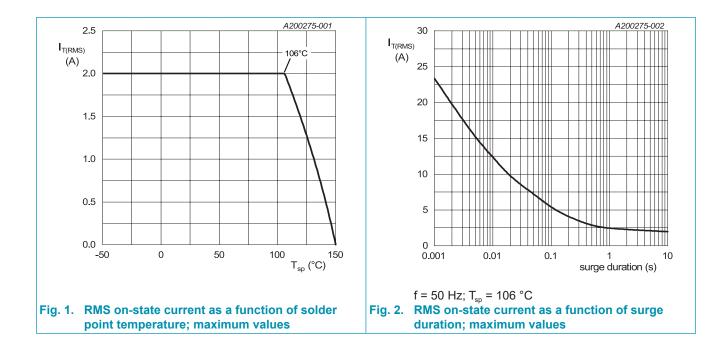
Type number	Marking codes	
	Assembly factory: d	Assembly factory: L
BT232W-800ET	Jdxxx 232W8E	JLxxx 232W8E

# 8. Limiting values

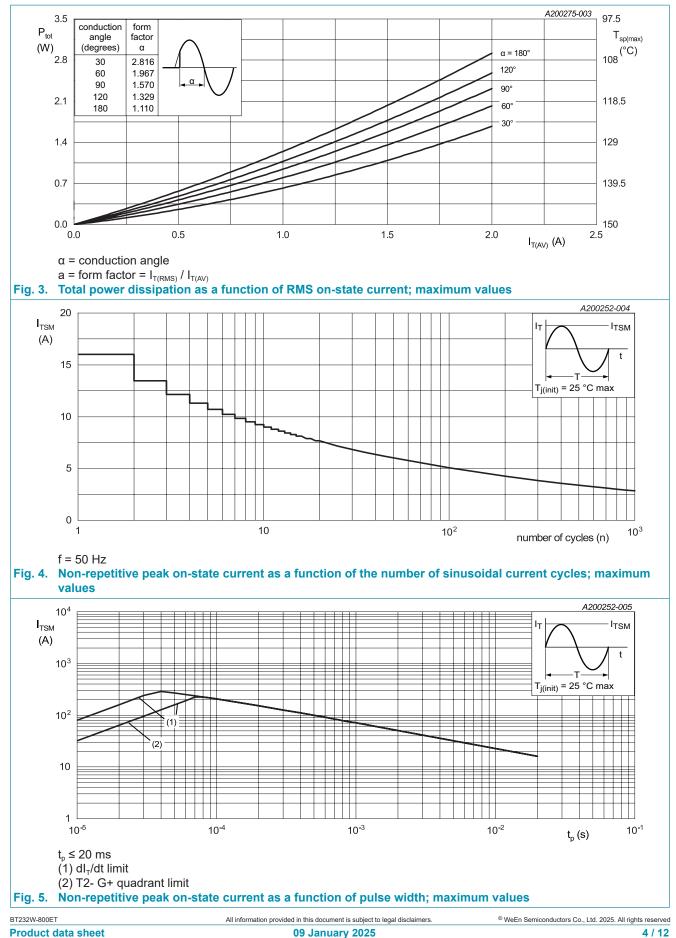
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage			800	V
$V_{\text{RRM}}$	repetitive peak reverse voltage			800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T <sub>sp</sub> ≤ 106 °C; <u>Fig 1; Fig 2</u> ; <u>Fig 3</u>		2	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; Fig 4; Fig 5		16	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms		18	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN		1.28	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 20 mA; T2+ G+		50	A/µs
		I <sub>G</sub> = 20 mA; T2+ G-		50	A/µs
		I <sub>G</sub> = 20 mA; T2- G-		50	A/µs
		I <sub>G</sub> = 20 mA; T2- G+		20	A/µs
I <sub>GM</sub>	peak gate current			1	А
P <sub>GM</sub>	peak gate power			2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period		0.1	W
T <sub>stg</sub>	storage temperature			-40 to 150	°C
Tj	operating junction temperature			-40 to 150	°C



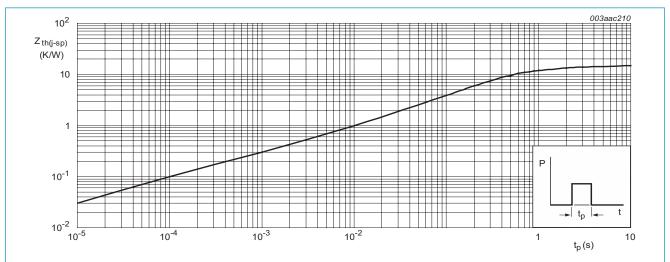
**BT232W-800ET 4Q Triac** 



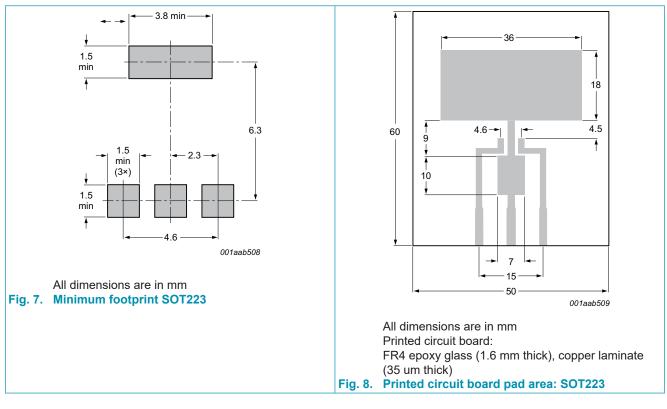
# 9. Thermal characteristics

### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	full cycle; <u>Fig 6</u>		-	-	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	full cycle; printed circuit board mounted; minimum footprint; <u>Fig 7</u>		-	156	-	K/W
		full cycle; printed circuit board mounted; pad area; Fig 8		-	70	-	K/W



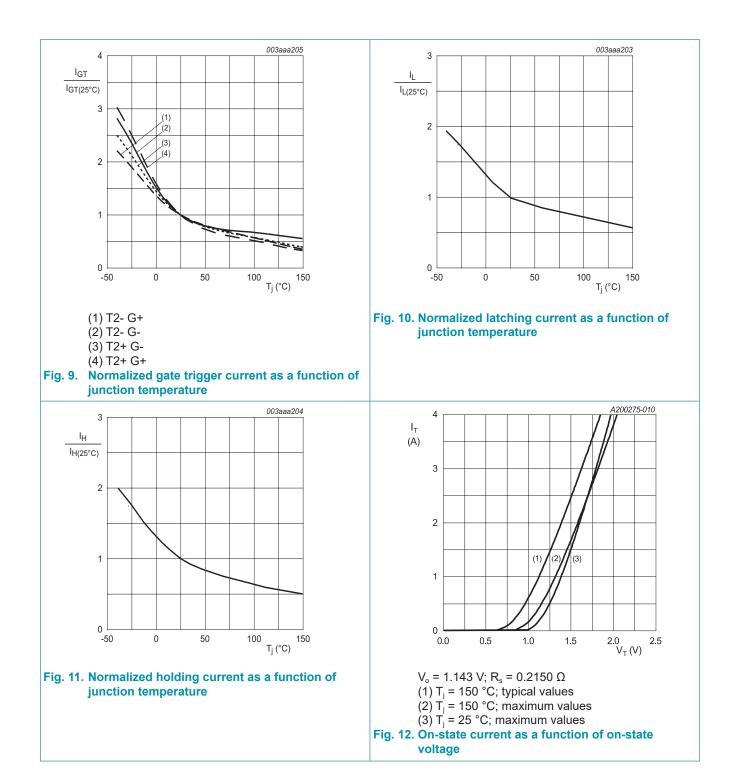
### Fig. 6. Transient thermal impedance from junction to solder point as a function of pulse width



# **10. Characteristics**

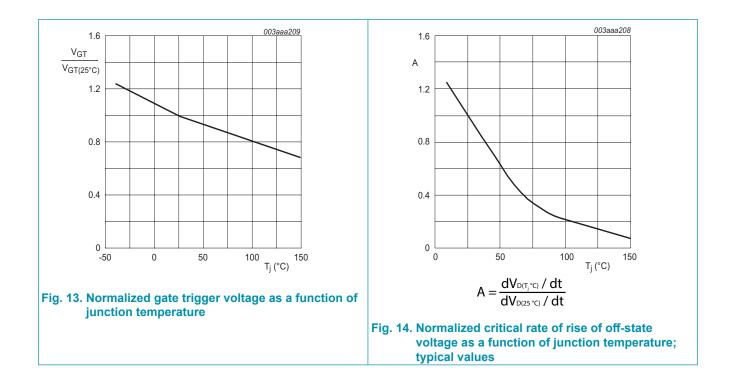
Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	-	10	mA
		$\begin{array}{c c c c c c c c c c c c c c c c c c c $	-	10	mA		
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$		-	-	10 m	mA
I <sub>L</sub>	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		-	-	15	mA
		$V_{D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; Fig. 10		-	-	25	mA
		$V_{D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; Fig. 10		-	-	15	mA
		$V_{D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; Fig. 10		-	-	15	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>		-	-	10	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 2 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>		-	1.3	1.6	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 13		-	-	1	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 150 °C		0.2	-	-	V
I <sub>D</sub>	off-state current	$V_{\rm D}$ = 800 V; T <sub>j</sub> = 25 °C		-	-	10	μA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 150 °C		-	-	1	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 800 V; T <sub>j</sub> = 25 °C		-	-	10	μA
		V <sub>R</sub> = 800 V; T <sub>j</sub> = 150 °C		-	-	1	mA
Dynamic	characteristics			1			
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 110 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit; Fig. 14		50	-	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 110 \text{ °C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$		2	-	-	V/µs

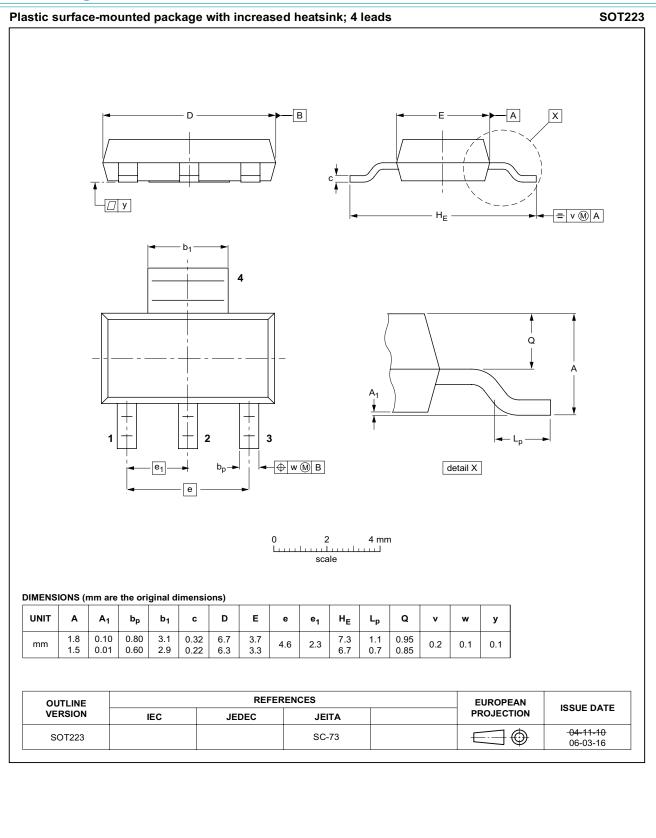


### **WeEn Semiconductors**

BT232W-800ET 4Q Triac



## **11. Package outline**



### BT232W-800ET 4Q Triac

# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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#### **4Q Triac**

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